

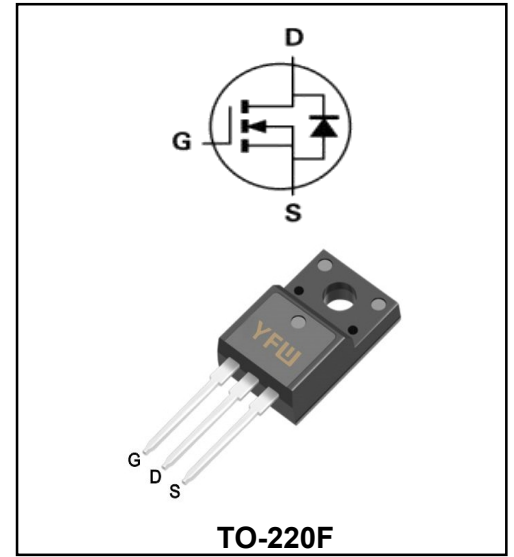
**650V N-channel Super Junction MOSFET**

**MAIN CHARACTERISTICS**

<b>I<sub>D</sub></b>	11A
<b>V<sub>DSS</sub></b>	650V
<b>R<sub>DS(on)-typ(@V<sub>GS</sub>=10V)</sub></b>	<380mΩ (Type:340mΩ)

**APPLICATIONS**

- † Solar inverters
- † LCD/LED/PDP TV
- † Telecom/Server Power supplies
- † AC-DC Power Supply



**Mechanical Data**

- † Case: Molded plastic
- † Mounting Position: Any
- † Molded Plastic: UL Flammability Classification Rating 94V-0
- † Lead free in compliance with EU RoHS 2011/65/EU directive
- † Solder bath temperature 275°C maximum, 10s per JESD 22-B106

**Maximum Ratings at Tc=25°C unless otherwise specified**

Characteristics	Symbols	Value	Units
Drain-Source Voltage	V <sub>DS</sub>	650	V
Gate-Source Voltage	V <sub>GS</sub>	±30	V
Continue Drain Current	I <sub>D</sub>	11	A
Pulsed Drain Current (Note1)	I <sub>DM</sub>	31.8	A
Power Dissipation	P <sub>D</sub>	84.5	W
Single Pulse Avalanche Energy (Note1)	E <sub>AS</sub>	220	mJ
Operating Temperature Range	T <sub>J</sub>	-55 to +150	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C
Thermal Resistance, Junction to Case	R <sub>θJC</sub>	1.48	°C/W
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	62	°C/W

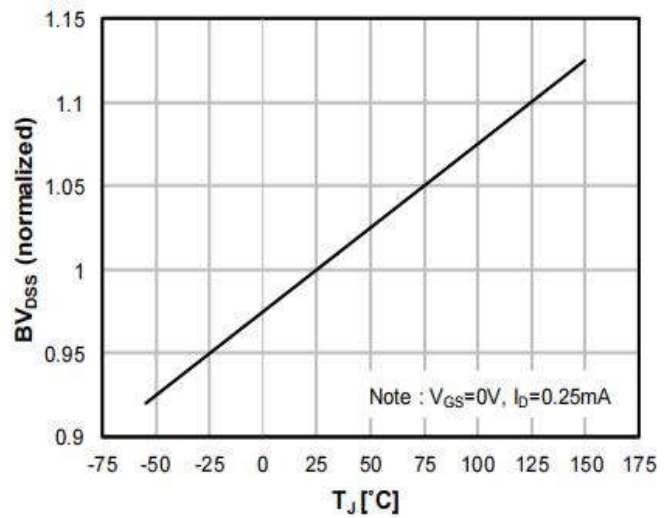
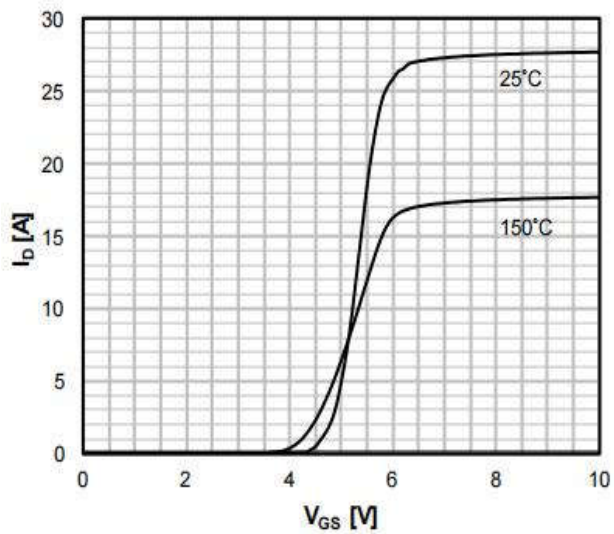
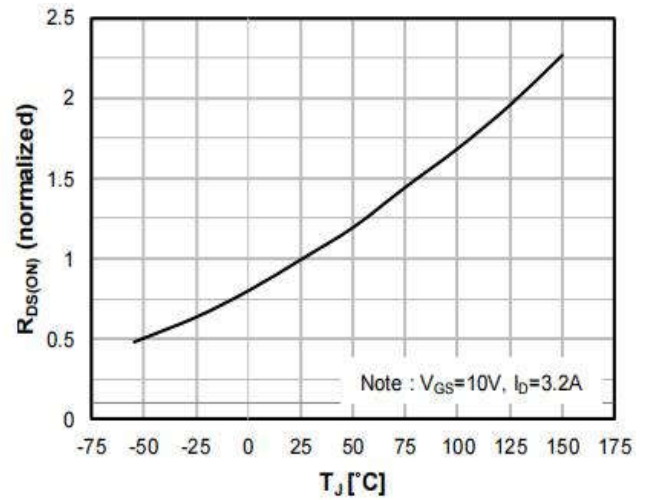
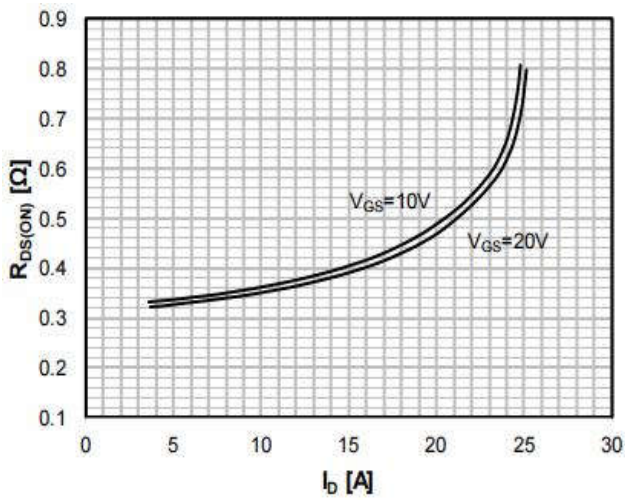
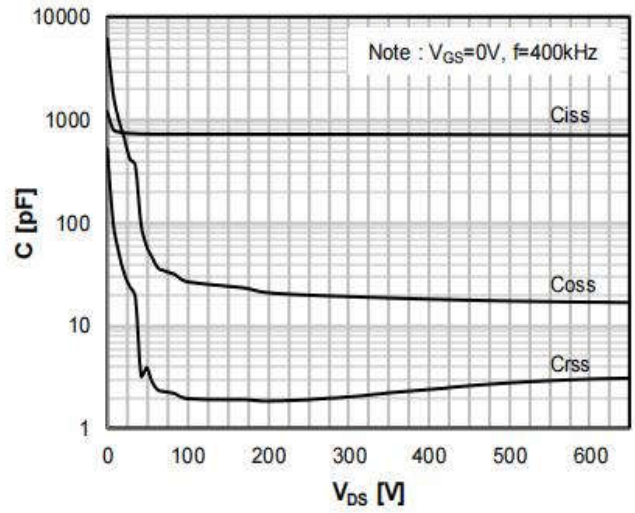
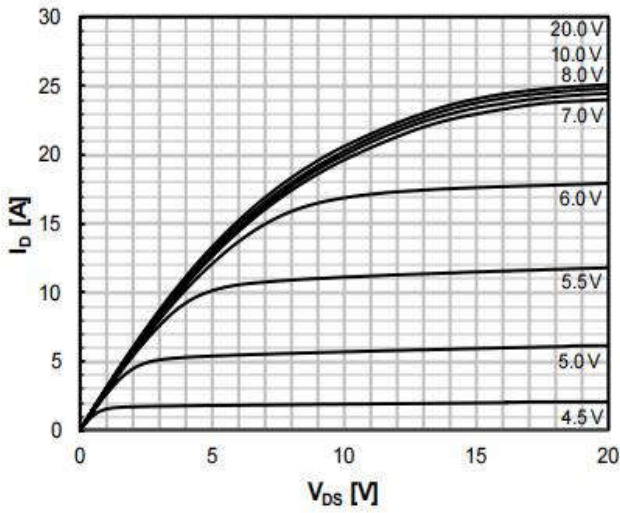
Note1:Pulse test: 300 μs pulse width, 2 % duty cycle

**Maximum Ratings at Tc=25°C unless otherwise specified**

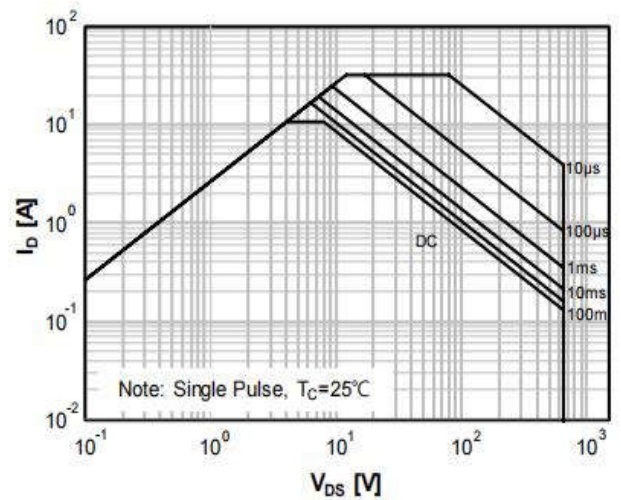
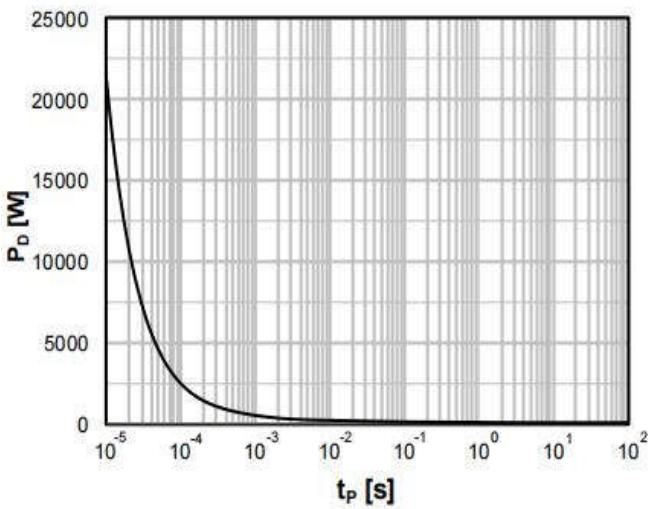
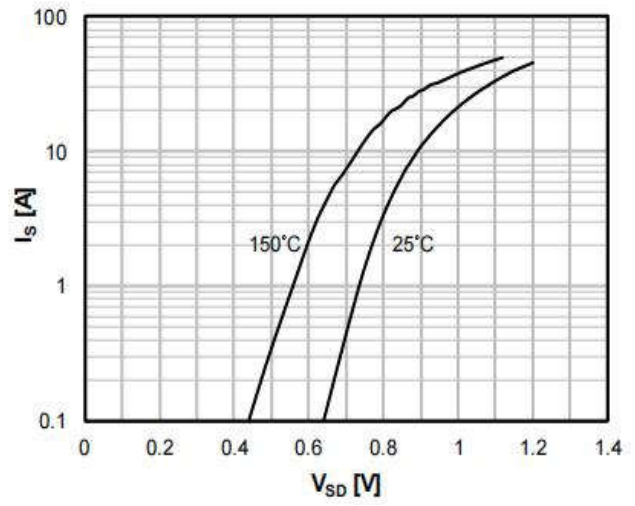
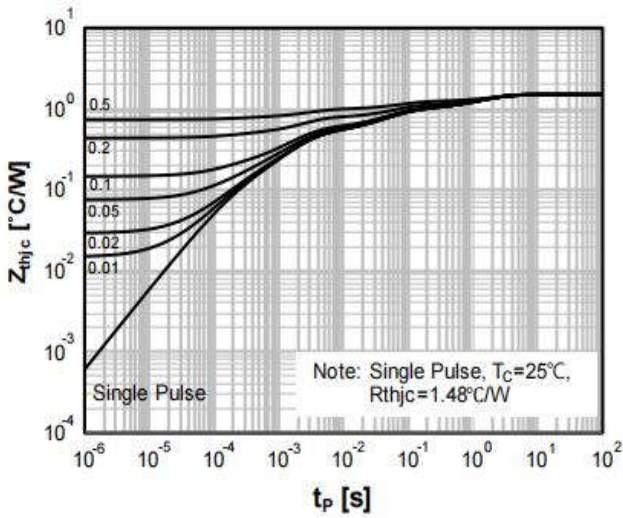
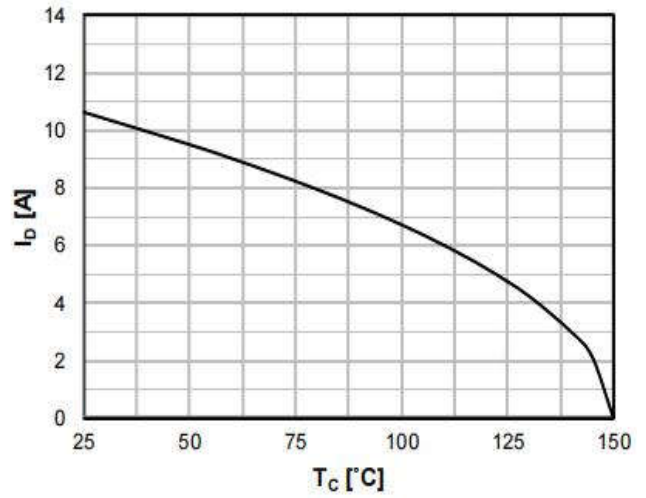
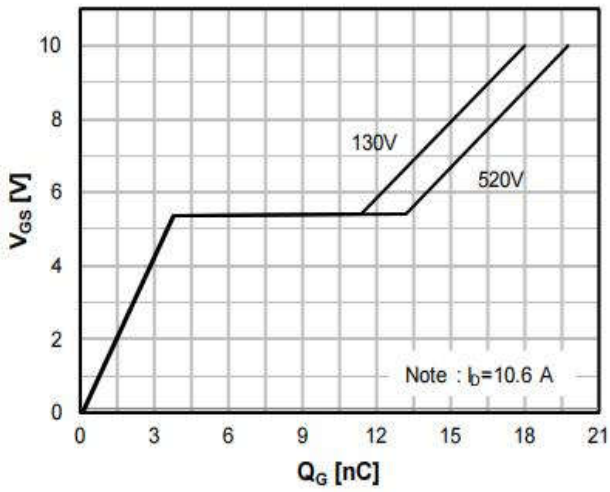
Characteristics	Test Condition	Symbols	Min	Typ	Max	Units
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}, I_D = 250\ \mu\text{A}$	$BV_{DSS}$	650	-	-	V
Drain-Source Leakage Current	$V_{DS} = 650\text{ V}, V_{GS} = 0\text{ V}$	$I_{DSS}$	-	-	1	$\mu\text{A}$
Gate Leakage Current	$V_{GS} = \pm 30\text{ V}, V_{DS} = 0\text{ V}$	$I_{GSS}$	-	-	$\pm 100$	nA
Gate-Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\ \mu\text{A}$	$V_{GS(th)}$	2	-	4	V
Drain-Source On-State Resistance	$V_{GS} = 10\text{ V}, I_D = 1\text{ A}$	$R_{DS(on)}$	-	340	380	m $\Omega$
Input Capacitance	$V_{GS} = 0\text{ V}, V_{DS} = 50\text{ V},$ $f = 400\text{ KHz}$	$C_{iss}$	-	747	-	pF
Output Capacitance		$C_{oss}$	-	55	-	
Reverse Transfer Capacitance		$C_{rss}$	-	3.3	-	
Turn-on Delay Time	$I_D = 10.6\text{ A}, V_{DD} = 325\text{ V},$ $V_{GS} = 10\text{ V}, R_G = 25\ \Omega$	$t_{d(ON)}$	-	18	-	nS
Rise Time		$t_r$	-	31	-	
Turn-Off Delay Time		$t_{d(OFF)}$	-	65	-	
Fall Time		$t_f$	-	28	-	
Total Gate Charge	$I_D = 10.6\text{ A}, V_{DS} = 520\text{ V},$ $V_{GS} = 10\text{ V}$	$Q_G$	-	20	-	nC
Gate to Source Charge		$Q_{GS}$	-	3.7	-	
Gate to Drain Charge		$Q_{GD}$	-	9	-	
Reverse recovery time	$I_{SD} = 10.6\text{ A}, V_{DD} = 100\text{ V},$ $di/dt = 100\text{ A}/\mu\text{s}$	$t_{rr}$	-	323	-	ns
Reverse recovery current		$I_{rr}$	-	17.5	-	A
Reverse recovery charge		$Q_{rr}$	-	2.8	-	$\mu\text{C}$
Drain-Source Diode Forward Voltage	$V_{GS} = 0\text{ V}, I_S = 10.6\text{ A},$ $T_J = 25^\circ\text{C}$	$V_{SD}$	-	1.4	-	v

 Note2: Pulse test: 300  $\mu\text{s}$  pulse width, 2 % duty cycle

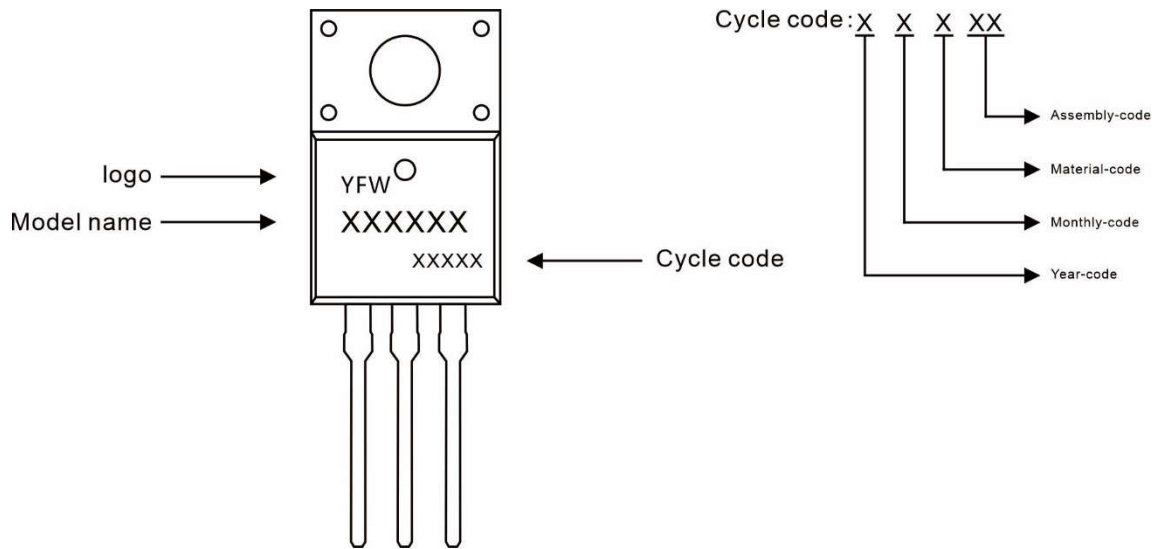
Ratings and Characteristic Curves



Ratings and Characteristic Curves



**Marking Diagram**



**Ordering information**

Model name	Package	Unit Weight	Base Quantity	Packing Quantity
YFW65R380AF	TO-220F	0.06oz(1.74g)	50pcs/tube	1000PCS/Box 5000PCS/Carton

**Package Dimensions**

**TO-220F**

Symbol	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.50	4.90	0.177	0.193
A1	2.34	2.74	0.092	0.108
A2	2.66	2.86	0.105	0.113
b	0.75	0.85	0.030	0.033
b1	1.24	1.44	0.049	0.057
c	0.40	0.60	0.016	0.024
D	10.00	10.32	0.394	0.406
E	15.75	16.05	0.620	0.632
e	2.44	2.64	0.096	0.104
e1	4.88	5.28	0.192	0.208
F	3.10	3.5	0.122	0.138
L	13.50	13.90	0.531	0.547
L1	2.90	3.30	0.114	0.130
Φ	3.10	3.30	0.122	0.130

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